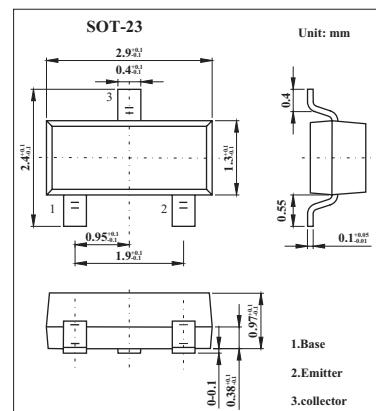


PNP Switching Transistor

BSR18A

■ Features

- Low current (max. 100 mA).
- Low voltage (max. 40 V).



■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-40	V
Collector-emitter voltage	V _{CCEO}	-40	V
Emitter-base voltage	V _{EBO}	-6	V
Collector current (DC)	I _C	-100	mA
Peak collector current	I _{CM}	-200	mA
Peak base current	I _{BM}	-100	mA
Total power dissipation	P _{tot}	250	mW
Storage temperature	T _{stg}	-65 to +150	°C
Junction temperature	T _j	150	°C
Operating ambient temperature	T _{amb}	-65 to +150	°C
Thermal resistance from junction to ambient *	R _{th(j-a)}	500	K/W

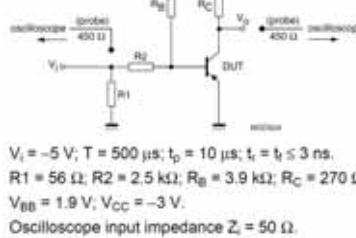
* Transistor mounted on an FR4 printed-circuit board.

BSR18A

■ Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise specified.

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Collector cutoff current	I_{CBO}	$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V}$			-50	nA
Emitter cutoff current	I_{EBO}	$I_C = 0 \text{ A}; V_{EB} = -6 \text{ V}$			-50	nA
DC current gain *	h_{FE}	$V_{CE} = -1 \text{ V}; I_C = -0.1 \text{ mA}$	60			
		$V_{CE} = -1 \text{ V}; I_C = -1 \text{ mA}$	80			
		$V_{CE} = -1 \text{ V}; I_C = -10 \text{ mA}$	100		300	
		$V_{CE} = -1 \text{ V}; I_C = -50 \text{ mA}$	60			
		$V_{CE} = -1 \text{ V}; I_C = -100 \text{ mA}$	30			
Collector-emitter saturation voltage *	V_{CEsat}	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$			-200	mV
		$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$			-200	mV
Base-emitter saturation voltage *	V_{BESat}	$I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$	-650		-850	mV
		$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$			-950	mV
Collector capacitance	C_C	$I_E = i_E = 0 \text{ A}; V_{CB} = -5 \text{ V}; f = 1 \text{ MHz}$			4.5	pF
Emitter capacitance	C_E	$I_C = i_C = 0 \text{ A}; V_{EB} = -500 \text{ mV}; f = 1 \text{ MHz}$			10	pF
Transition frequency	f_T	$I_C = -10 \text{ mA}; V_{CE} = -20 \text{ V}; f = 100 \text{ MHz}$	250			MHz
Noise figure	NF	$I_C = -100 \mu\text{A}; V_{CE} = -5 \text{ V}; R_s = 1 \text{ k}\Omega; f = 10 \text{ Hz to } 15.7 \text{ kHz}$			4	dB
Turn-on time	t_{on}	$I_{Con} = -10 \text{ mA}; I_{Bon} = -1 \text{ mA}; I_{Boff} = 1 \text{ mA}$			65	ns
Delay time	t_d				35	ns
Rise time	t_r				35	ns
Turn-off time	t_{off}				300	ns
Storage time	t_s				225	ns
Fall time	t_f				75	ns

* Pulse test: $t_p \leq 300 \mu\text{s}$; $d \leq 0.02$.



■ Marking

Marking	T92
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